

# N-Channel Super Junction Power MOSFET ${\ensuremath{\mathrm{III}}}$

### **General Description**

The series of devices use advanced trench gate super junction technology and design to provide excellent R<sub>DS(ON)</sub> with low gate charge. This super junction MOSFET fits the industry's AC-DC SMPS requirements for PFC, AC/DC power conversion, and industrial power applications.

#### Features

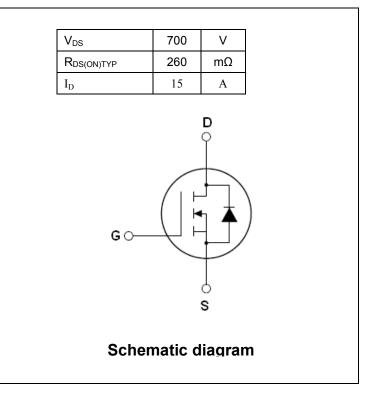
- •New technology for high voltage device
- •Low on-resistance and low conduction losses
- ●Small package
- ●Ultra Low Gate Charge cause lower driving requirements
- ●100% Avalanche Tested
- ●ROHS compliant

### Application

- Power factor correction (PFC)
- Switched mode power supplies(SMPS)
- Uninterruptible Power Supply (UPS)

Package Marking And Ordering Information						
Device	Device Package	Marking				
NCE70T260D	TO-263	NCE70T260D				
NCE70T260	TO-220	NCE70T260				
NCE70T260F	TO-220F	NCE70T260F				

### Table 1. Absolute Maximum Ratings (T<sub>c</sub>=25℃)





TO-263

TO-220

TO-220F

Table 1. Absolute Maximum Katings (1 <sub>C</sub> =25 C)						
Parameter	Symbol	NCE70T260D NCE70T260	NCE70T260F	Unit		
Drain-Source Voltage (VGs=0V)	Vds	700		V		
Gate-Source Voltage (V <sub>DS=0</sub> V) AC (f>1 Hz)	Vgs	±30		V		
Continuous Drain Current at Tc=25°C	I <sub>D (DC)</sub>	15	15*	А		
Continuous Drain Current at Tc=100°C	I <sub>D (DC)</sub>	10	10*	А		
Pulsed drain current (Note 1)	DM (pluse)	60	60*	А		
Maximum Power Dissipation(Tc=25°C)	PD	131	33.2	W		
Derate above 25°C		1.05	0.265	W/°C		
Single pulse avalanche energy (Note 2)	Eas	304		mJ		
Avalanche current <sup>(Note 1)</sup>	I <sub>AR</sub>	3		А		
Repetitive Avalanche energy , $t_{\text{AR}}$ limited by $T_{\text{jmax}}$ (Note 1)	E <sub>AR</sub>	1.6		mJ		



# NCE70T260D,NCE70T260,NCE70T260F

Parameter	Symbol	NCE70T260D NCE70T260	NCE70T260F	Unit
Drain Source voltage slope, $V_{DS} \leqslant 480 V$ ,	dv/dt	50		V/ns
Reverse diode dv/dt, $V_{DS} \leqslant 480 V, I_{SD} < I_D$	dv/dt	15		V/ns
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55	+150	°C

\* limited by maximum junction temperature

#### Table 2. Thermal Characteristic

Parameter		Symbol	NCE70T260D NCE70T260	NCE	E70T26	60F	Unit
Thermal Resistance, Junction-to-Case (Maxin	num)	R <sub>thJC</sub>	0.95		3.76		°C /W
Thermal Resistance, Junction-to-Ambient (M	laximum)	R <sub>thJA</sub>	62	80			°C /W
Table 3. Electrical Characteristics (	( <b>TA=25</b> ℃	unless otherv	vise noted)				
Parameter	Symbo	ol Co	ndition	Min	Тур	Max	Unit
On/off states		·	·		•		
Drain-Source Breakdown Voltage	BV/see	\/O	V/ L 250 u A	700			V

Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	700			V
Zero Gate Voltage Drain Current(Tc=25°C)	I <sub>DSS</sub>	V <sub>DS</sub> =700V,V <sub>GS</sub> =0V			1	μA
Zero Gate Voltage Drain Current(Tc=125℃)	I <sub>DSS</sub>	V <sub>DS</sub> =700V,V <sub>GS</sub> =0V			100	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V			±100	nA
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	3	3.5	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =8A		260	290	mΩ
Dynamic Characteristics				•		
Input Capacitance	C <sub>iss</sub>	N/ F0)/// 0)/		1210	1400	pF
Output Capacitance	Coss	- V <sub>DS</sub> =50V,V <sub>GS</sub> =0V,		74		pF
Reverse Transfer Capacitance	Crss	F=1.0MHz		0.2		pF
Total Gate Charge	Qg	N/ 400)// 454		24.7	42	nC
Gate-Source Charge	Q <sub>gs</sub>	- V <sub>DS</sub> =480V,I <sub>D</sub> =15A,		8.2		nC
Gate-Drain Charge	Q <sub>gd</sub>	– V <sub>GS</sub> =10V		8.5		nC
Switching times			•	•		
Turn-on Delay Time	t <sub>d(on)</sub>			15		nS
Turn-on Rise Time	tr	V <sub>DD</sub> =420V,I <sub>D</sub> =8A,		10		nS
Turn-Off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> =2.3Ω,V <sub>GS</sub> =10V		57		nS
Turn-Off Fall Time	t <sub>f</sub>			9		nS
Source- Drain Diode Characteristics				•		
Source-drain current(Body Diode)	I <sub>SD</sub>	T 05°O			15	А
Pulsed Source-drain current(Body Diode)	I <sub>SDM</sub>	– T <sub>C</sub> =25°C			60	А
Forward On Voltage	V <sub>SD</sub>	Tj=25°C,I <sub>SD</sub> =15A,V <sub>GS</sub> =0V		0.9	1.2	V
Reverse Recovery Time	t <sub>rr</sub>			240		nS
Reverse Recovery Charge	Q <sub>rr</sub>	Tj=25°C,I <sub>F</sub> =7.5A,di/dt=100A/µs		2		uC
Peak Reverse Recovery Current	Irrm			17		А
		1	•	•		

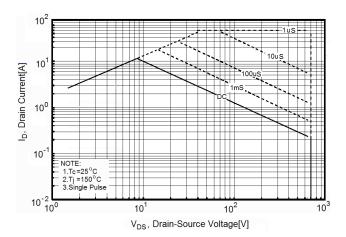
Notes 1.Repetitive Rating: Pulse width limited by maximum junction temperature

2. Tj=25°C,VDD=50V,VG=10V, R\_G=25\Omega



## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (curves)

#### Figure1. Safe operating area



#### Figure3. Source-Drain Diode Forward Voltage

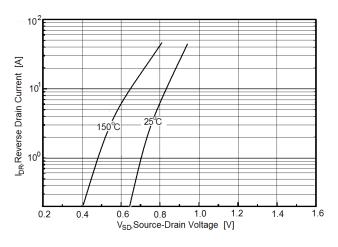
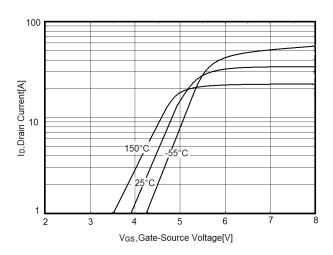


Figure 5. Transfer characteristics



#### Figure 2. Safe operating area for TO-220F

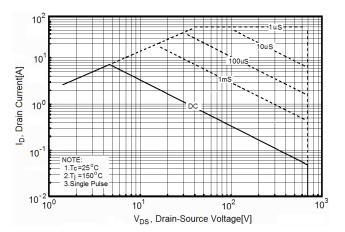


Figure4. Output characteristics

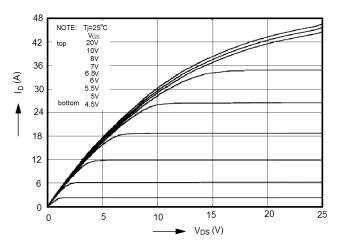
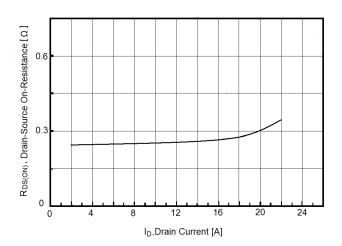


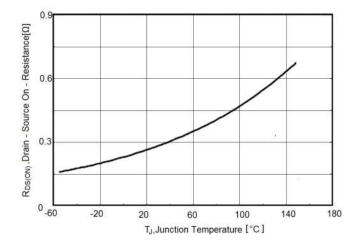
Figure6. Static drain-source on resistance





#### Figure7. R<sub>DS(ON)</sub> vs Junction Temperature

#### Figure8. BV<sub>DSS</sub> vs Junction Temperature



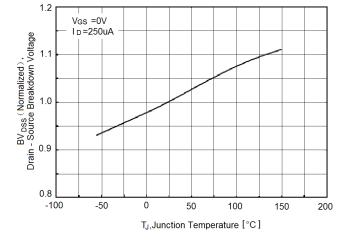


Figure9. Maximum I<sub>D</sub> vs Junction Temperature

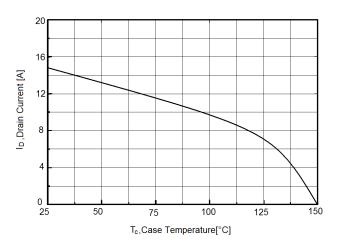
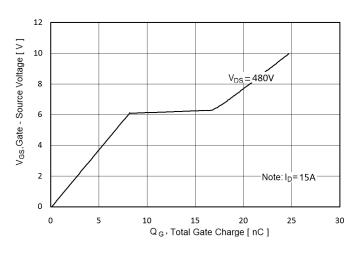


Figure10. Gate charge waveforms





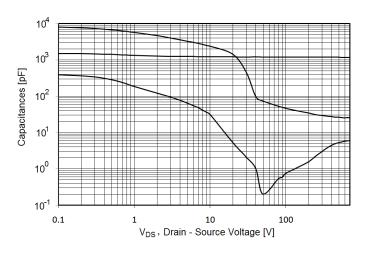
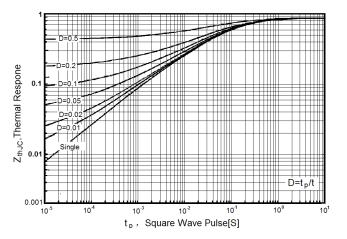
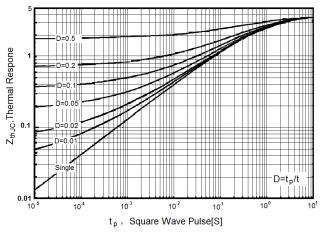


Figure12. Transient Thermal Impedance





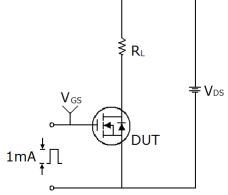
## Figure13. Transient Thermal Impedance for TO-220F

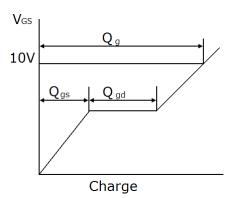




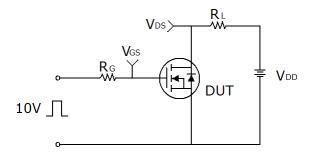
# Test circuit

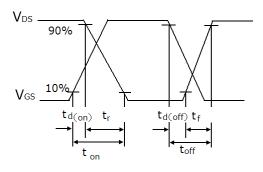
1) Gate charge test circuit & Waveform



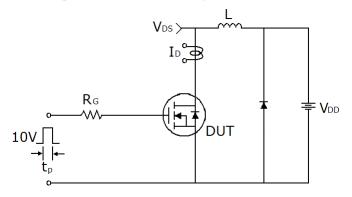


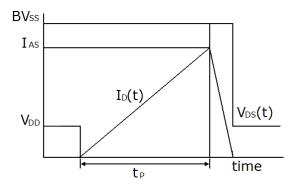
2) Switch Time Test Circuit:





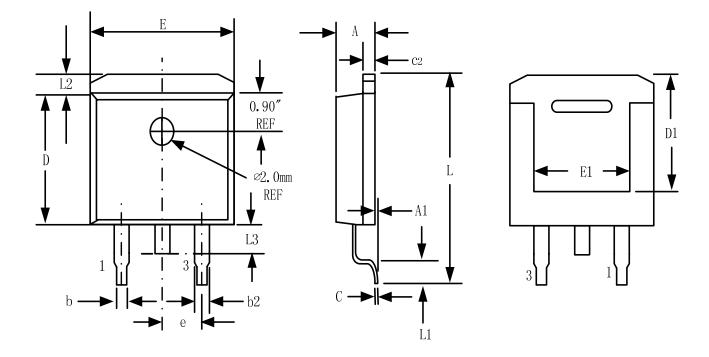
3) Unclamped Inductive Switching Test Circuit & Waveforms







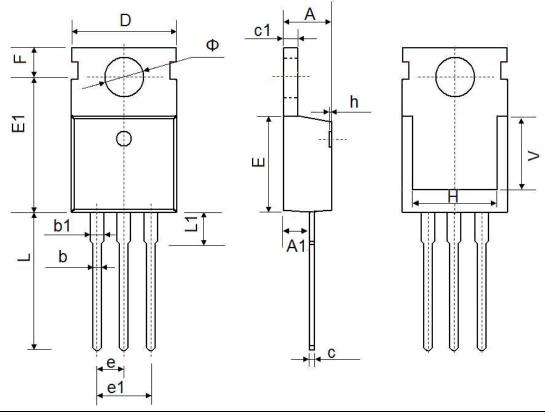
# **TO-263-3L Package Information**



Symbol	Dimensions	In Millimeters	Dimensions	s In Inches
Symbol	Min.	Max.	Min.	Max.
A	4.32	4.57	0.170	0.180
A1	-	0.25		0.010
b	0.71	0.94	0.028	0.037
b2	1.15	1.40	0.045	0.055
С	0.46	0.61	0.018	0.024
c2	1.22	1.40	0.048	0.055
D	8.89	9.40	0.350	0.370
D1	8.01	8.23	0.315	0.324
E	10.04	10.28	0.395	0.405
E1	7.88	8.08	0.310	0.318
е	2.54	4 BSC	0.100	BSC
L	14.73	15.75	0.580	0.620
L1	2.29	2.79	0.090	0.110
L2	1.15	1.39	0.045	0.055
L3	1.27	1.77	0.050	0.070



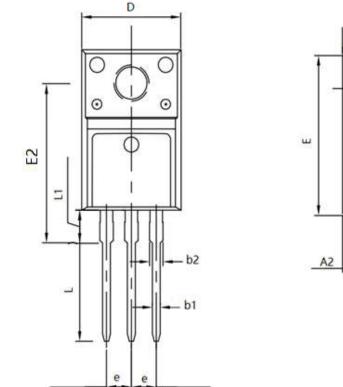
# **TO-220-3L-C Package Information**

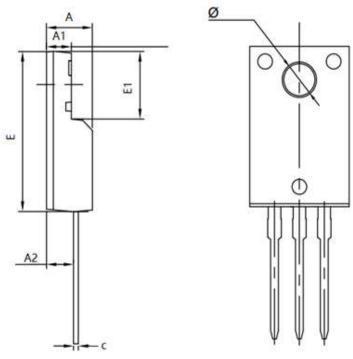


Symbol	Dimensions	In Millimeters	Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
A	4.400	4.600	0.173	0.181
A1	2.250	2.550	0.089	0.100
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
с	0.330	0.650	0.013	0.026
c1	1.200	1.400	0.047	0.055
D	9.910	10.250	0.390	0.404
E	8.9500	9.750	0.352	0.384
E1	12.650	12.950	0.498	0.510
е	2.540 TYP.		0.100	TYP.
e1	4.980	5.180	0.196	0.204
F	2.650	2.950	0.104	0.116
Н	7.900	8.100	0.311	0.319
h	0.000	0.300	0.000	0.012
L	12.900	13.400	0.508	0.528
L1	2.850	3.250	0.112	0.128
V	7.500	) REF.	0.295	REF.
Ф	3.400	3.800	0.134	0.150



# **TO-220F Package Information**





Symbol	Dimensions	In Millimeters	Dimension	s In Inches
	Min.	Max.	Min.	Max.
А	4.500	4.900	0.177	0.193
A1	2.340	2.740	0.092	0.108
A2	2.560	2.960	0.101	0.117
b1	0.700	0.900	0.028	0.035
b2	1.180	1.580	0.046	0.062
С	0.400	0.600	0.016	0.024
D	9.960	10.360	0.392	0.408
E	15.670	15.970	0.617	0.629
E1	6.500	6.900	0.256	0.272
E2	15.500	16.100	0.610	0.634
e	2.54	0 TYP	0.100	) TYP
Φ	3.080	3.280	0.121	0.129
L	12.640	13.240	0.498	0.521
L1	3.030	3.430	0.119	0.135



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